



DC COMPONENTS CO., LTD.

RECTIFIER SPECIALISTS

**1N5391
THRU
1N5399**

TECHNICAL SPECIFICATIONS OF SILICON RECTIFIER

VOLTAGE RANGE - 50 to 1000 Volts CURRENT - 1.5 Amperes

FEATURES

- * Low cost
- * Low leakage
- * Low forward voltage drop
- * High current capability

MECHANICAL DATA

- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Lead: MIL-STD-202E, Method 208 guaranteed
- * Polarity: Color band denotes cathode end
- * Mounting position: Any
- * Weight: 0.38 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

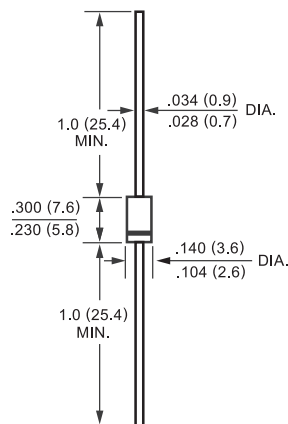
Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.



DO-15



Dimensions in inches and (millimeters)

		SYMBOL	1N5391	1N5392	1N5393	1N5395	1N5397	1N5398	1N5399	UNITS
Maximum Recurrent Peak Reverse Voltage		V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage		V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current .375*(9.5mm) lead length at T _L = 70°C		I _O	1.5							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)		I _{FSM}	50							Amps
Maximum Instantaneous Forward Voltage at 1.5A DC		V _F	1.4							Volts
Maximum DC Reverse Current	@ T _A = 25°C	I _R	5.0							uAmps
at Rated DC Blocking Voltage	@ T _A = 100°C		500							
Maximum Full Load Reverse Current Average, Full Cycle .375*(9.5mm) lead length at T _L = 75°C			30							uAmps
Typical Junction Capacitance (Note)		C _J	20							pF
Typical Thermal Resistance		R θ _{J A}	50							°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-65 to + 175							°C

NOTES : Measured at 1 MHz and applied reverse voltage of 4.0 volts

RATING AND CHARACTERISTIC CURVES (1N5391 THRU 1N5399)

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

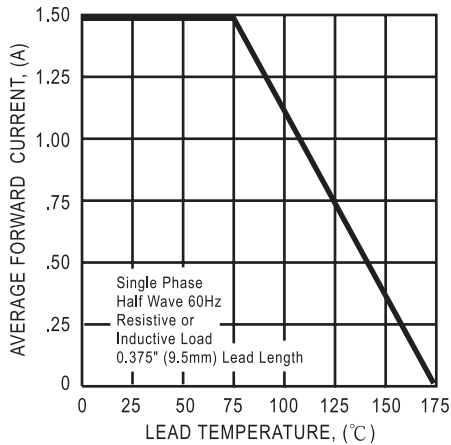


FIG. 2 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

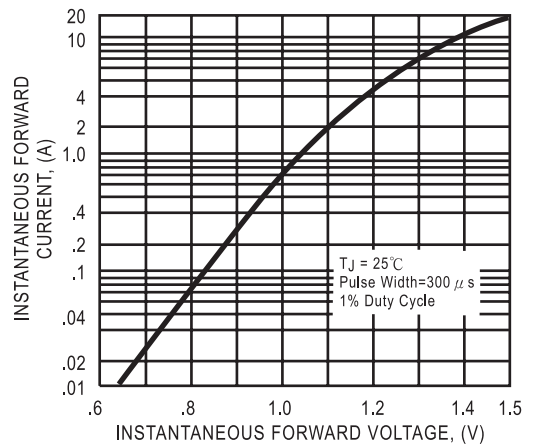


FIG. 3 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

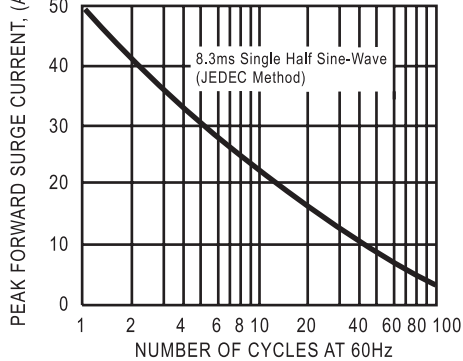


FIG. 4 - TYPICAL JUNCTION CAPACITANCE

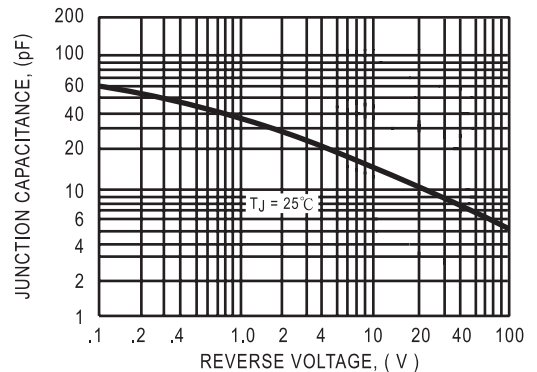
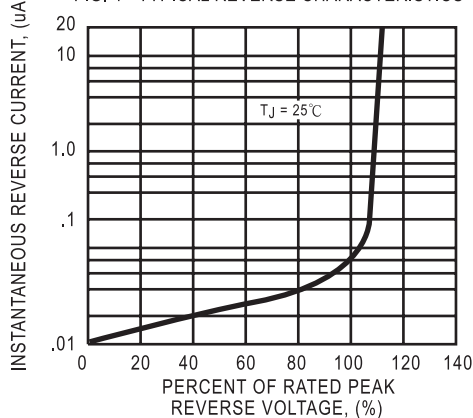


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS



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